NPN Transistor TO-92







Pin Configuration:

- 1. Collector
- 2. Base
- 3. Emitter

Features:

- · NPN silicon planar switching transistors
- · Fast switching devices exhibiting short turn-off and low saturation voltage characteristics
- · General purpose switching and amplifier applications

Absolute Maximum Ratings

| Description | Symbol | Value | Unit | |
|---|-----------------------------------|-------------|-------------|--|
| Collector-Emitter Voltage | V _{CEO} | 40 | | |
| Collector-Base Voltage | V _{CBO} | 60 | V | |
| Emitter-Base Voltage | V _{EBO} | 6 | | |
| Collector Current Continuous | I _C | 200 | mA | |
| Power Dissipation at T _a = 25°C Derate above 25°C | D | 625 5 | mW mW/°C | |
| Power Dissipation at T _c = 25°C Derate above 25°C | P _D | 1.5 12 | W mW/°C | |
| Operating and Storage Junction Temperature Range | T _j , T _{stg} | -55 to +150 | °C | |

Thermal Resistance

| Junction to Case | R _{th (j-c)} | 83.3 | °C/W |
|---------------------|-----------------------|------|------|
| Junction to Ambient | R _{th (j-a)} | 200 | C/VV |





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Electrical Characteristics ($T_a = 25$ °C unless otherwise specified)

| Description | Symbol | Test Condition | 2N3904 | Unit | |
|--------------------------------------|------------------------|--|---------------------------------------|------|--|
| Collector-Emitter Voltage | *V _{CEO} | I _C = 10mA, I _B = 0 | >40 | | |
| Collector-Base Voltage | V_{CBO} | $I_{\rm C} = 10 \mu A, I_{\rm E} = 0$ | >60 | V | |
| Emitter-Base Voltage | V _{EBO} | $I_{E} = 10 \mu A, I_{C} = 0$ | >6 | | |
| Collector-Cut off Current | I _{CEX} | V 20V V 2V | -50 | n ^ | |
| Base Current | I _{BL} | $V_{CE} = 30V, V_{EB} = 3V$ | <50 | nA | |
| DC Current Gain | *h _{FE} | $I_{C} = 0.1 \text{mA}, V_{CE} = 1 \text{V}$ $I_{C} = 1 \text{mA}, V_{CE} = 1 \text{V}$ $I_{C} = 10 \text{mA}, V_{CE} = 1 \text{V}$ $I_{C} = 50 \text{mA}, V_{CE} = 1 \text{V}$ $I_{C} = 100 \text{mA}, V_{CE} = 1 \text{V}$ | >40 >70 100 - 300 >60 >30 | - | |
| Collector Emitter Saturation Voltage | *V _{CE (sat)} | I _C = 10mA, I _B = 1mA | <0.2 <0.3 | V | |
| Base Emitter Saturation Voltage | *V _{BE (sat)} | I _C = 50mA, I _B = 5mA | 0.65 - 0.85 <0.95 | V | |

Small Signal Characteristic

| Transistors Frequency | f _T | I _C = 10mA, V _{CE} = 20V, f = 100MHz | >300 | MHz |
|---------------------------|-----------------|--|-----------|--------------------|
| Output Capacitance | C _{ob} | V _{CB} = 5V, I _E = 0, f = 1MHz | <4 | pF |
| Input Capacitance | C _{ib} | $V_{BE} = 0.5V, I_{C} = 0, f = 1MHz All f = kHz$ | <8 | |
| Small Signal Current Gain | h _{fe} | | 100 - 400 | - |
| Input Impedance | h _{ie} | - 1m/ \/ - 10\/ | 1 - 10 | kΩ |
| Output Admittance | h _{oe} | $I_C = 1$ mA, $V_{CE} = 10$ V | 1 - 40 | μΩ |
| Voltage Feedback Ratio | h _{re} | | 0.5 - 0.8 | × 10 ⁻⁴ |
| Noise Figure | NF | I _C = 100μA, V _{CE} = 5V | <5 | dB |

Switching Time

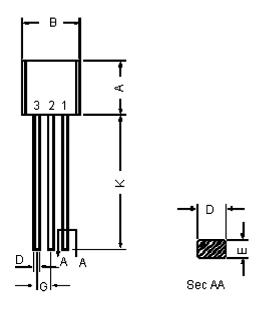
| Delay Time | t _d | $V_{CC} = 3V, V_{BE} = 0.5V$ | <35 | |
|--------------|----------------|--|-------------|----|
| Rise Time | t _r | I _C = 10mA, I _{B1} = 1mA | \ 35 | |
| Storage Time | t _s | $V_{CC} = 3V, I_{C} = 10mA$ $I_{B1} = I_{B2} = 1mA$ | <200 | ns |
| Fall Time | t _f | - | <50 | |

^{*}Pulse Condition: = 300µs, Duty Cycle = 2%



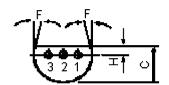
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| Dimensions | Min. | Max. |
|------------|------|------|
| А | 4.32 | 5.33 |
| В | 4.45 | 5.2 |
| С | 3.18 | 4.19 |
| D | 0.41 | 0.55 |
| Е | 0.35 | 0.5 |
| F | 5 | 0 |
| G | 1.14 | 1.4 |
| Н | | 1.53 |
| K | 12.7 | - |

Dimensions: Millimetres



Pin Configuration:

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Part Number Table

| Part Number |
|-------------|
| 2N3904 |
| _ |

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